

# Non-Inverting 3-State Buffer NLV17SZ126

The NLV17SZ126 is a single non-inverting buffer in tiny footprint packages.

#### **Features**

- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- 2.3 ns  $t_{PD}$  at  $V_{CC} = 5 \text{ V (typ)}$
- Inputs/Outputs Overvoltage Tolerant up to 5.5 V
- I<sub>OFF</sub> Supports Partial Power Down Protection
- Source/Sink 24 mA at 3.0 V
- Available in SC-88A, SOT-553, and SOT-953 Packages
- Chip Complexity < 100 FETs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol

#### MARKING DIAGRAMS



SC-88A DF SUFFIX CASE 419A





SOT-553 XV5 SUFFIX CASE 463B





SOT-953 P5 SUFFIX CASE 527AE



XX = Specific Device Code

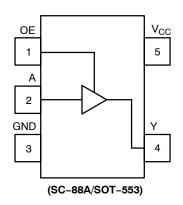
M = Date Code\*
■ Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information on page 7 of this data sheet.



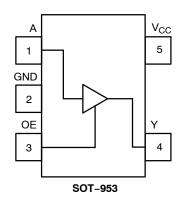


Figure 2. Pinout (Top View)

## PIN ASSIGNMENT (SC-88A/SOT-553)

Pin	Function
1	OE
2	А
3	GND
4	Υ
5	V <sub>CC</sub>

#### PIN ASSIGNMENT (SOT-953)

Pin	Function
1	Α
2	GND
3	OE
4	Y
5	V <sub>CC</sub>

#### **FUNCTION TABLE**

Inp	Output	
OE	Α	Υ
Н	L	L
Н	Н	Н
L	X	Z

X = Don't Care

#### **MAXIMUM RATINGS**

Symbol	Chai	racteristics	Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +7.0 -0.5 to +7.0	V
	DC Output Voltage	(NL17SZ126P5T5G-L22088 Only)	-0.5 to V <sub>CC</sub> + 0.5	
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-50	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-50	mA
	DC Output Diode Current	(NL17SZ126P5T5G-L22088 Only)	±50	
I <sub>OUT</sub>	DC Output Source/Sink Current	±50	mA	
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or	±100	mA	
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C	
TL	Lead Temperature, 1 mm from Case	for 10 secs	260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	SC-88A SOT-553 SOT-953	377 324 254	°C/W
P <sub>D</sub>	Power Dissipation in Still Air	SC-88A SOT-553 SOT-953	332 386 491	mW
MSL	Moisture Sensitivity		Level 1	-
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V <sub>ESD</sub>	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	٧
I <sub>Latchup</sub>	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.

2. Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.

3. HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to

- EIA/JESD22–A115–A (Machine Model) be discontinued per JEDEC/JEP172A.

  4. Tested to EIA/JESD78 Class II.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Cha	racteristics	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage		1.65	5.5	V
V <sub>IN</sub>	DC Input Voltage		0	5.5	V
V <sub>OUT</sub>	DC Output Voltage	Active–Mode (High or Low State) Tri–State Mode (Note 1) Power–Down Mode ( $V_{\rm CC}$ = 0 V)	0 0 0	V <sub>CC</sub> 5.5 5.5	V
	DC Output Voltage	(NL17SZ126P5T5G-L22088 Only)	0	V <sub>CC</sub>	
T <sub>A</sub>	Operating Temperature Range		-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	V <sub>CC</sub> = 3.0 V to 3.6 V V <sub>CC</sub> = 4.5 V to 5.5 V	0	100 20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

#### DC ELECTRICAL CHARACTERISTICS

			V <sub>CC</sub>	T,	<sub>λ</sub> = 25°(	С	-55°C ≤ T	<sub>A</sub> ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
V <sub>IH</sub>	High-Level Input Voltage	e	1.65 to 1.95	0.75 x V <sub>CC</sub>			0.75 x V <sub>CC</sub>		V
			2.3 to 5.5	0.70 x V <sub>CC</sub>			0.70 x V <sub>CC</sub>		
$V_{IL}$	Low-Level Input Voltage	)	1.65 to 1.95			0.25 x V <sub>CC</sub>		0.25 x V <sub>CC</sub>	٧
			2.3 to 5.5			0.30 x V <sub>CC</sub>		0.30 x V <sub>CC</sub>	
V <sub>OH</sub>	High-Level Output Voltage	$\begin{split} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OH} = -100  \mu\text{A} \\ &I_{OH} = -4 \text{ mA} \\ &I_{OH} = -8 \text{ mA} \\ &I_{OH} = -12 \text{ mA} \\ &I_{OH} = -16 \text{ mA} \\ &I_{OH} = -24 \text{ mA} \\ &I_{OH} = -32 \text{ mA} \end{split}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	V <sub>CC</sub> - 0.1 1.29 1.9 2.2 2.4 2.3 3.8	V <sub>CC</sub> 1.4 2.1 2.4 2.7 2.5 4.0	- - - - -	V <sub>CC</sub> - 0.1 1.29 1.9 2.2 2.4 2.3 3.8	- - - - -	V
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OL} = 100 \ \mu\text{A} \\ I_{OL} = 4 \ \text{mA} \\ I_{OL} = 8 \ \text{mA} \\ I_{OL} = 12 \ \text{mA} \\ I_{OL} = 16 \ \text{mA} \\ I_{OL} = 24 \ \text{mA} \\ I_{OL} = 32 \ \text{mA} \end{array}$	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	- - - - -	- 0.08 0.2 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55	- - - - - -	0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	1.65 to 5.5	-	-	±0.1	-	±1.0	μΑ
l <sub>OZ</sub>	3-State Output Leakage Current	V <sub>OUT</sub> = 0 V to 5.5 V	1.65 to 5.5	-	-	±0.5	-	±5.0	μΑ
l <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	-	-	1.0	-	10	μΑ
	Power Off Leakage Current (NL17SZ126P5T5G- L22088 Only)	V <sub>IN</sub> = 5.5 V	0	-	_	1.0	-	10	μΑ
Icc	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	-	1.0	-	10	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

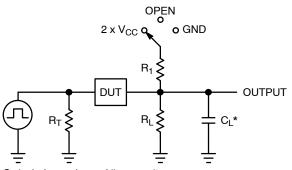
#### **AC ELECTRICAL CHARACTERISTICS**

			V <sub>CC</sub>	T,	<sub>A</sub> = 25°	С	-55°C ≤ T	<sub>Δ</sub> ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
t <sub>PLH,</sub>	Propagation Delay, A to Y	$R_L$ = 1 M $\Omega$ , $C_L$ = 15 pF	1.65 to 1.95	-	6.0	10	-	10.5	ns
t <sub>PHL</sub>	(Figures 3 and 4)	$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	2.3 to 2.7	-	3.4	7.5	-	8.0	
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	3.0 to 3.6	-	2.5	5.2	-	5.5	
		$R_L = 500 \Omega$ , $C_L = 50 pF$		-	2.9	5.7	-	6.0	
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	4.5 to 5.5	-	2.0	4.5	-	4.8	
		$R_L = 500 \Omega$ , $C_L = 50 pF$		_	2.3	5.0	-	5.3	
t <sub>PZH</sub> ,	Output Enable Time,		1.65 to 1.95	-	6.5	9.5	-	10	ns
t <sub>PZL</sub>	OE to Y (Figures 3 and 4)		2.3 to 2.7	-	3.6	8.5	-	9.0	
			3.0 to 3.6	-	2.8	6.2	-	6.5	
			4.5 to 5.5	-	2.0	5.5	-	5.8	
t <sub>PHZ</sub> ,	Output Disable Time,		1.65 to 1.95	-	5.0	10	-	10.5	ns
t <sub>PLZ</sub>	OE to Y (Figures 3 and 4)		2.3 to 2.7	-	3.3	8.0	-	8.5	
			3.0 to 3.6	_	2.7	5.7	-	6.0	
			4.5 to 5.5	-	2.6	4.7	_	5.0	

#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_{IN} = 0 \text{ V or } V_{CC}$	2.5	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 5.5 \text{ V}, V_{IN} = 0 \text{ V or } V_{CC}$	2.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	10 MHz, $V_{CC}$ = 3.3 V, $V_{IN}$ = 0 V or $V_{CC}$ 10 MHz, $V_{CC}$ = 5.5 V, $V_{IN}$ = 0 V or $V_{CC}$	9 11	pF

<sup>5.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.



Test	Switch Position	C <sub>L</sub> , pF	$R_L, \Omega$	R <sub>1</sub> , Ω	
t <sub>PLH</sub> / t <sub>PHL</sub>	Open	See AC Characteristics Table			
t <sub>PLZ</sub> / t <sub>PZL</sub>	2 x V <sub>CC</sub>	50	500	500	
t <sub>PHZ</sub> / t <sub>PZH</sub>	GND	50	500	500	

X = Don't Care

 $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega)$ 

f = 1 MHz

Figure 3. Test Circuit

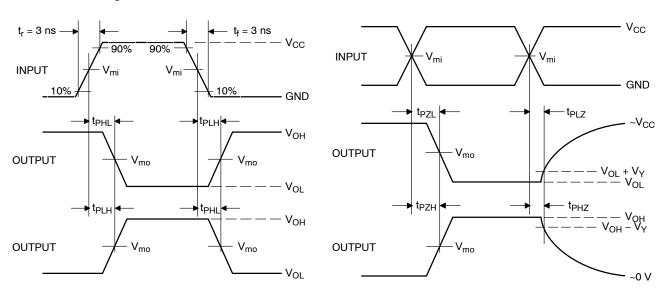


Figure 4. Switching Waveforms

		V <sub>m</sub>	V <sub>mo</sub> , V		
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub> , t <sub>PZH</sub> , t <sub>PHZ</sub>	V <sub>Y</sub> , V	
1.65 to 1.95	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15	
2.3 to 2.7	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15	
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3	
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3	

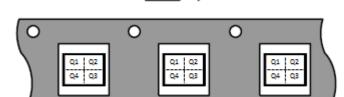
#### **DEVICE ORDERING INFORMATION**

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
NLV17SZ126DFT2G*	SC-88A	M2	Q4	3000 / Tape & Reel
NL17SZ126DFT2G-L22038	SC-88A	M2	Q4	3000 / Tape & Reel
NL17SZ126XV5T2G-L22087	SOT-553	M2	Q4	4000 / Tape & Reel
NL17SZ126P5T5G-L22088	SOT-953	R (Rotated 180° CW)	Q2	8000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### Pin 1 Orientation in Tape and Reel

#### Direction of Feed



<sup>\*</sup>NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

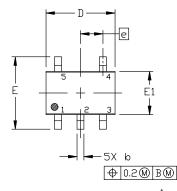
#### **PACKAGE DIMENSIONS**

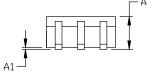
#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

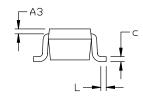
#### NOTES:

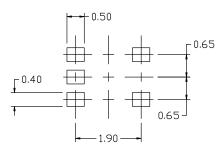
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. 419A-01 DBSDLETE, NEW STANDARD 419A-02
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,
  PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,
  OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

DIM	MILLIMETERS				
ויונע	MIN.	N□M.	MAX.		
А	0.80	0.95	1.10		
A1			0.10		
A3		0,20 REF			
b	0.10	0.20	0.30		
C	0.10		0.25		
D	1.80	2.00	2.20		
Е	2.00	2.10	2.20		
E1	1.15	1.25	1.35		
е	0.65 BSC				
L	0.10	0.15	0.30		









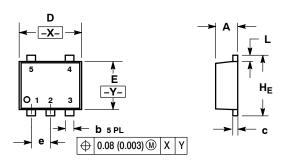
## RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

#### **PACKAGE DIMENSIONS**

#### **SOT-553, 5 LEAD**

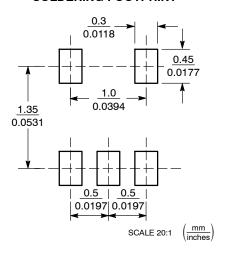
CASE 463B ISSUE C



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM
  THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.13	0.18	0.003	0.005	0.007
D	1.55	1.60	1.65	0.061	0.063	0.065
E	1.15	1.20	1.25	0.045	0.047	0.049
е	0.50 BSC			0.020 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.55	1.60	1.65	0.061	0.063	0.065

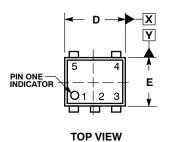
#### **SOLDERING FOOTPRINT\***

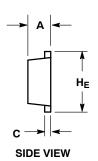


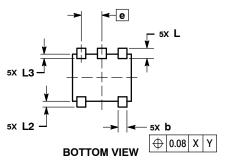
\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

#### SOT-953 CASE 527AE **ISSUE E**





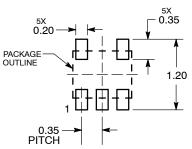


#### NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994
- CONTROLLING DIMENSION: MILLIMETERS
  MAXIMUM LEAD THICKNESS INCLUDES LEAD
  FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL DIMENSIONS D AND E DO NOT INCLUDE MOLD
- FLASH, PROTRUSIONS, OR GATE BURRS.

		MILLIMETERS					
	DIM	MIN	NOM	MAX			
	Α	0.34	0.37	0.40			
	<b>b</b> 0.10		0.15	0.20			
	<b>C</b> 0.07		0.12	0.17			
	<b>D</b> 0.95		1.00	1.05			
[	Е	0.75	0.80	0.85			
	е	0.35 BSC					
	HE	0.95	1.00	1.05			
	L	0.175 REF					
-[	L2	0.05	0.10	0.15			
	L3			0.15			

#### **SOLDERING FOOTPRINT\***



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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